

FEATURES:

- 3V to 3.6V operating voltage
- 48MHz to 160MHz output frequency range
- Input from fundamental crystal oscillator or external source
- Internal PLL feedback (loading feedback output relative to other outputs, adjusts propagation delay between REF inputs and outputs)
- Select inputs (S[1:0]) for FB divide selection (multiply ratio of 2, 3, 4, 4.25, 5, 6, 6.25, and 8)
- Low jitter
- PLL bypass for testing and power-down control (S1 = H, S0 = H, powers part down <500µA)
- Available in TSSOP package

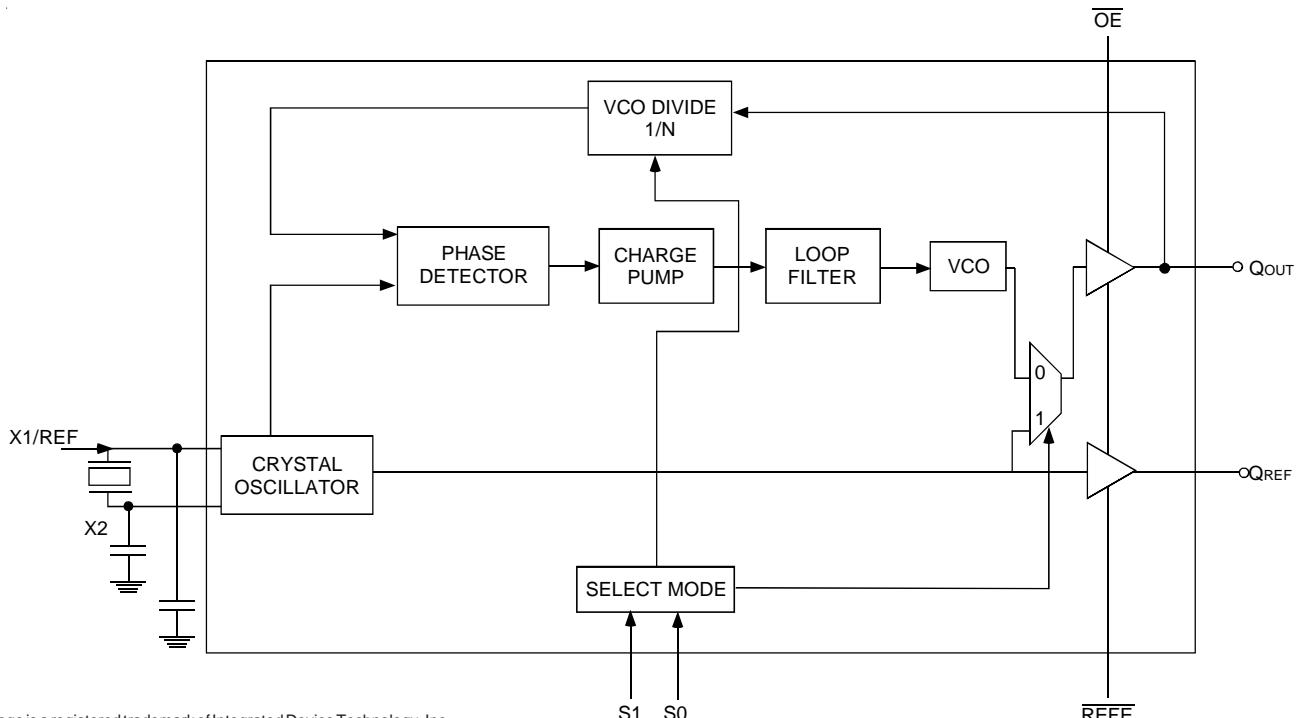
APPLICATIONS:

- Gigabit ethernet
- Router
- Network switches
- SAN
- Instrumentation
- Fibre channel

DESCRIPTION:

The IDT5V926 is a low-cost, low skew, low jitter, and high-performance clock synthesizer with a reference clock from lower frequency crystal or clock input. It has been specially designed to interface with Gigabit Ethernet and Fast Ethernet applications by providing a 125MHz clock from 25MHz input. It can be programmed to provide output frequencies ranging from 48MHz to 160MHz, with input frequencies ranging from 6MHz to 80MHz.

The IDT5V926 includes an internal RC filter that provides excellent jitter characteristics and eliminates the need for external components. When using the optional crystal input, the chip accepts a 10 - 40MHz fundamental mode crystal with a maximum equivalent series resistance of 50Ω .

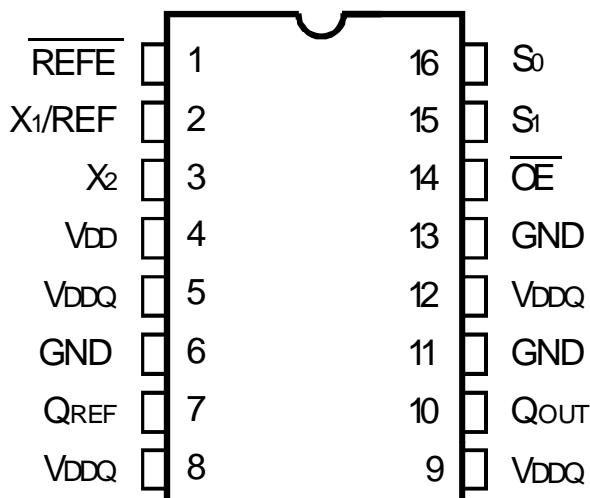
FUNCTIONAL BLOCK DIAGRAM


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INDUSTRIAL TEMPERATURE RANGE

APRIL 2003

PIN CONFIGURATION

TSSOP
TOP VIEW

CRYSTAL SPECIFICATION

The crystal oscillators should be fundamental mode quartz crystals; overtone crystals are not suitable. Crystal frequency should be specified for parallel resonance with 50Ω maximum equivalent series resonance. Crystal tuning capacitors should be connected from X1/REF to GND and from X2 to GND.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
V _{DD/VDDQ}	Supply Voltage to Ground	-0.5 to +4.6	V
V _I	Input Voltage	-0.5 to +4.6	V
I _O	Output Current	±50	mA
T _{STG}	Storage Temperature	-65 to +150	°C
T _J	Junction Temperature	150	°C

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

PIN DESCRIPTION

Pin Name	Type	Description
S[1:0]	I	Three level divider/mode select pins. Float to MID.
OE	I	Output enable bar. Outputs QOUT and QREF are tristated when HIGH. Set OE LOW for normal operation (has internal pull-down).
REFE	I	QREF enable input. QREF stopped LOW when HIGH. When set REFE LOW, the QREF is enabled (has internal pull-down).
X ₁ /REF	I	Crystal oscillator input or clock input
X ₂	I	Crystal oscillator output. Leave unconnected for clock input.
QOUT	O	Output at N*REF frequency
QREF	O	Output at REF frequency
V _{DDQ}	PWR	Power supply for the device outputs. Connect to V _{DD} on PCB.
V _{DD}	PWR	Power supply for the device core and inputs. Connect to V _{DD} on PCB.
GND	PWR	Ground supply

DIVIDE SELECTION TABLE⁽¹⁾

S ₁	S ₀	Divide-by-N Value	Mode
L	L	2	PLL
L	M	3	PLL
L	H	4	PLL
M	L	4.25	PLL
M	M	5	PLL
M	H	6	PLL
H	L	6.25	PLL
H	M	8	PLL
H	H	TEST	TEST ⁽²⁾

NOTES:

1. H = HIGH

M = MEDIUM

L = LOW

2. Test mode for low frequency testing. In this mode, REF clock bypasses the VCO (VCO powered down) and the crystal oscillator is powered down.

COMMON OUTPUT FREQUENCY EXAMPLES (MHz)

Output	48	60	64	72	75	80	90	100
Input	24	10	16	12	25	10	15	20
FB Divide Selection S[1:0]	LL	MH	LH	MH	LM	HM	MH	MM

Output	106.25	106.25	120	125	125	125	150	155.52
Input	17	25	15	20	25	62.5	25	19.44
FB Divide Selection S[1:0]	HL	ML	HM	HL	MM	LL	MH	HM

OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{DD} /V _{DDQ}	Power Supply Voltage	3	3.3	3.6	V
T _A	Operating Temperature	-40	25	+85	°C
C _L	Output Load Capacitance	—	—	15	pF
C _{IN}	Input Capacitance, OE, F = 1MHz, V _{IN} = 0V, T _A = 25°C	—	5	7	pF

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: T_A = -40°C to +85°C, V_{DD}/V_{DDQ} = 3.3V ±0.3V

Symbol	Parameter	Test Conditions		Min.	Typ.	Max	Unit
V _{IL}	Input LOW Voltage			—	—	0.8	V
V _{IH}	Input HIGH Voltage			2	—	—	V
V _{IHH}	Input HIGH Voltage	3-level input only		V _{DD} - 0.6	—	—	V
V _{IMM}	Input MID Voltage	3-level input only		V _{DD} /2 - 0.3	—	V _{DD} /2 + 0.3	V
V _{ILL}	Input LOW Voltage	3-level input only		—	—	0.6	V
I ₃	3-Level Input DC Current, S[1:0]	V _{IN} = V _{DD}	HIGH Level	—	—	+200	μA
		V _{IN} = V _{DD} /2	MID Level	-50	—	+50	
		V _{IN} = GND	LOW Level	-200	—	—	
I _{IH}	Input HIGH Current	V _{IN} = V _{DD}	OE, REFE	—	—	100	μA
		V _{IN} = V _{DD} , S[1:0] = HH	X1/REF	—	2	4	mA
V _{OL}	Output LOW Voltage	I _{OL} = 12mA		—	—	0.4	V
V _{OH}	Output HIGH Voltage	I _{OH} = -12mA		2.4	—	—	V

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Typ.	Max	Unit
I_{DD_PD}	Power Down Current	$V_{DD} = \text{Max.}$ $S[1:0] = \text{HH}$ $\overline{OE} = L; X_1/\text{REF} = L$ All outputs unloaded	—	—	500	μA
ΔI_{DD}	Supply Current per Input	$V_{DD} = \text{Max.}, V_{IN} = 3\text{V}$	—	—	30	μA
I_{DD}	Dynamic Supply Current	$V_{DD} = 3.6\text{V}$ $S[1:0] = \text{LL}$ $\overline{OE} = L$ $F_{OUT} = 150\text{MHz}$ All outputs unloaded	—	—	130	mA

NOTE:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

AC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
$t_{R,F}$	Rise Time, Fall Time	0.8V to 2V	Q_{OUT}	—	0.7	1.5	ns
			Q_{REF}	—	0.7	2	
d_T	Output/Duty Cycle	$V_T = V_{DD}/2$	Q_{OUT}	45	—	55	%
			Q_{REF}	40	—	60	
τ	Cycle - Cycle Jitter	$F_{OUT} = 106.25\text{MHz}$		- 100	—	100	ps
		$F_{OUT} = 125\text{MHz}$		- 75	—	75	
		$F_{OUT} = 155.52\text{MHz}$		- 75	—	75	
f_{OUT}	Output Frequency	—		48	—	160	MHz

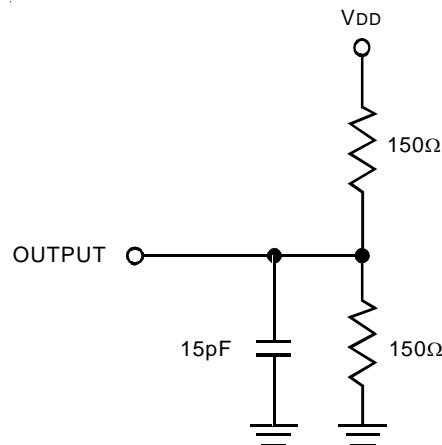
INPUT TIMING REQUIREMENTS

Symbol	Description ⁽¹⁾	Min.	Max.	Unit
$t_{R,F}$	Maximum input rise and fall time, 0.8V to 2V ⁽²⁾	—	10	ns/V
t_{PWC}	Input clock pulse, HIGH or LOW ⁽²⁾	2	—	ns
D_H	Input duty cycle ⁽²⁾	10	90	%
f_{OSC}	XTAL oscillator frequency	—	40	MHz
f_{IN}	Input frequency ⁽²⁾	48/N	160/N	MHz

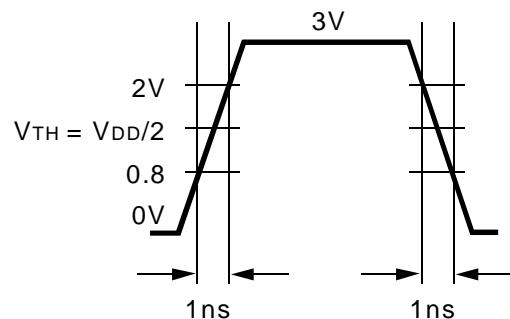
NOTES:

1. Where pulse width implied by D_H is less than the t_{PWC} limit, t_{PWC} limit applies.
 2. When using a clock input.

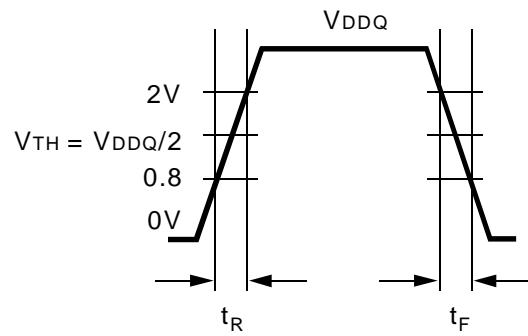
AC TEST LOADS AND WAVEFORMS



AC Test Load

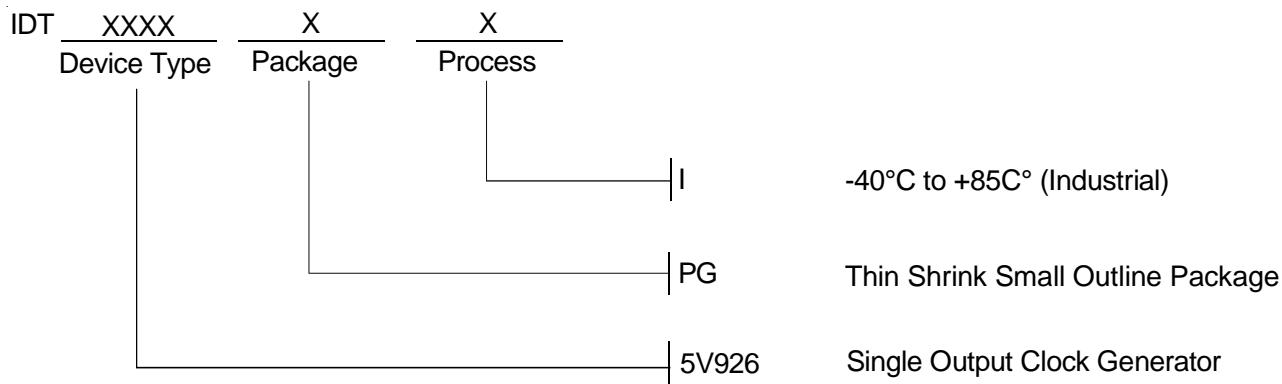


Input Test Waveform



Output Waveform

ORDERING INFORMATION



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